Preface

This issue of ECS Transactions contains the 55 papers presented at the Ninth Symposium on Thin Film Transistor Technologies (TFT 9), held in Honolulu, Hawaii, October 13-16, 2008. This symposium was sponsored by the Electronics and Photonics Division of the Electrochemical Society.

This symposium was organized into 9 sections: TFT-based Systems, TFT Devices, TFT Reliability, Advanced TFT Processes, Organic TFTs, Metal Oxide TFTs, TFTs on Flexible Substrates, New TFT Applications and Circuits, and Posters. Totally, 69 papers were presented orally and posted by authors from industry, research institutes and universities of 11 countries or regions, i.e., Canada, China, France, Hong Kong, Japan, Korea, Netherlands, Spain, Taiwan, UK, and USA.

In order to present papers in a coherent manner, this issue of ECS Transactions was edited into seven sections. All papers are published as original received without alteration of their technical contents except for the format.

The editor wishes to express his sincere appreciation to the following people for their involvement in organizing and conducting the symposium:

- authors and presenters of papers for their participation.
- co-organizers for their contributions in planning and coordinating the program.
- section co-chairs for their conducting the meeting.
- C.-H. Lin and M. R. Coan for their assistance in editing the volume.
- staffs of the Electrochemical Society for their administrative assistance in organizing the symposium and in publishing this volume.

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Facts about ECS

The Electrochemical Society (ECS) is an international, nonprofit, scientific, educational organization founded for the advancement of the theory and practice of electrochemistry, electrothermics, electronics, and allied subjects. The Society was founded in Philadelphia in 1902 and incorporated in 1930. There are currently over 7,000 scientists and engineers from more than 70 countries who hold individual membership; the Society is also supported by more than 100 corporations through Corporate Memberships.

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